

**ECE-656: Fall 2009**

**Lecture 22:  
Charged Impurity Scattering**

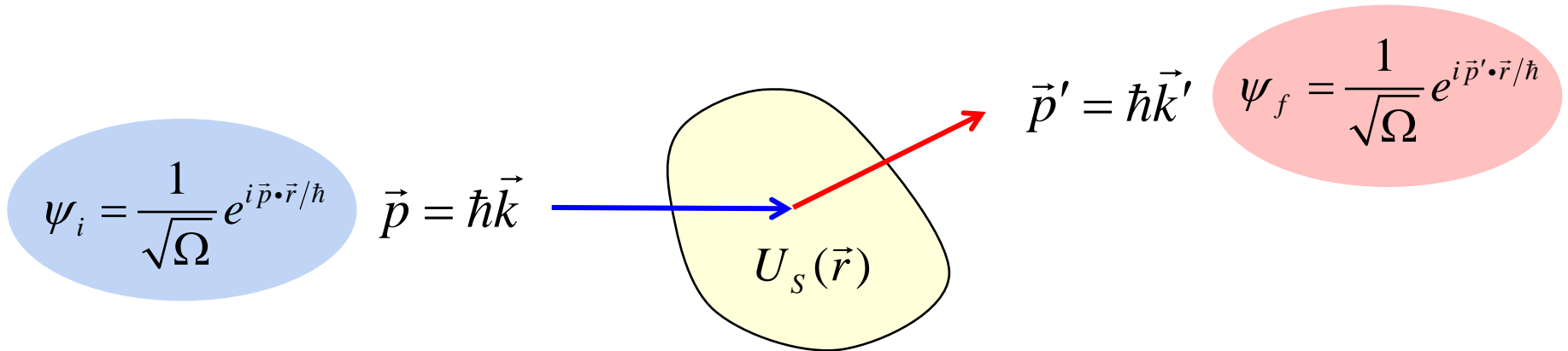
Professor Mark Lundstrom  
Electrical and Computer Engineering  
Purdue University, West Lafayette, IN USA

# outline

---

- 1) **Review**
- 2) Screening
- 3) Brooks-Herring approach
- 4) Conwell-Weisskopf approach
- 5) Discussion
- 6) Summary / Questions

# prescription



$$S(\vec{p}, \vec{p}') = \frac{2\pi}{\hbar} |H_{p'p}|^2 \delta(E' - E)$$

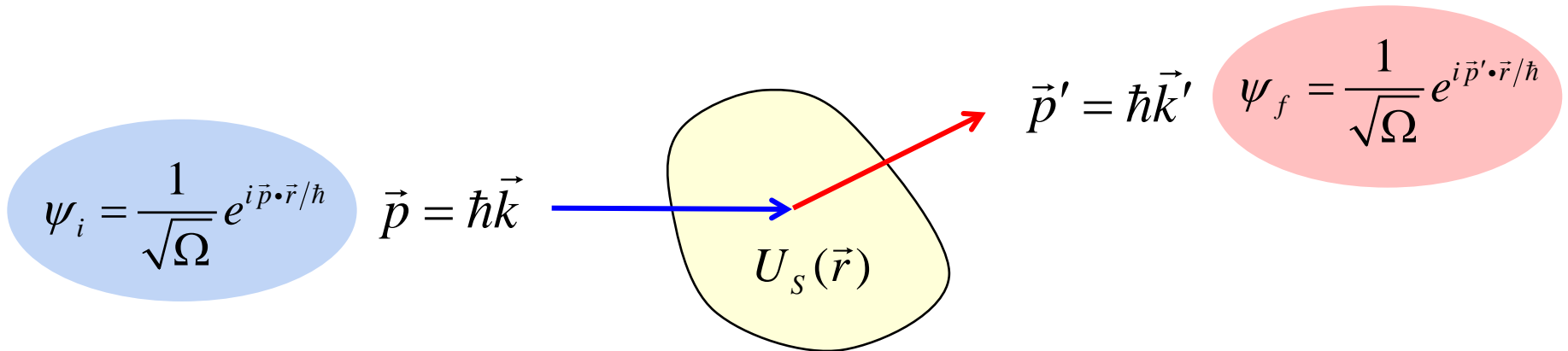
Time-independent scattering potential  $\rightarrow$  elastic scattering.

$$H_{\vec{p}', \vec{p}} = \int_{-\infty}^{+\infty} \psi_f^* U_S(\vec{r}) \psi_i d\vec{r}$$

Matrix element.

Initial and final states are plane waves  $\rightarrow$  assume that the overlap factor is 1.

# prescription (ii)



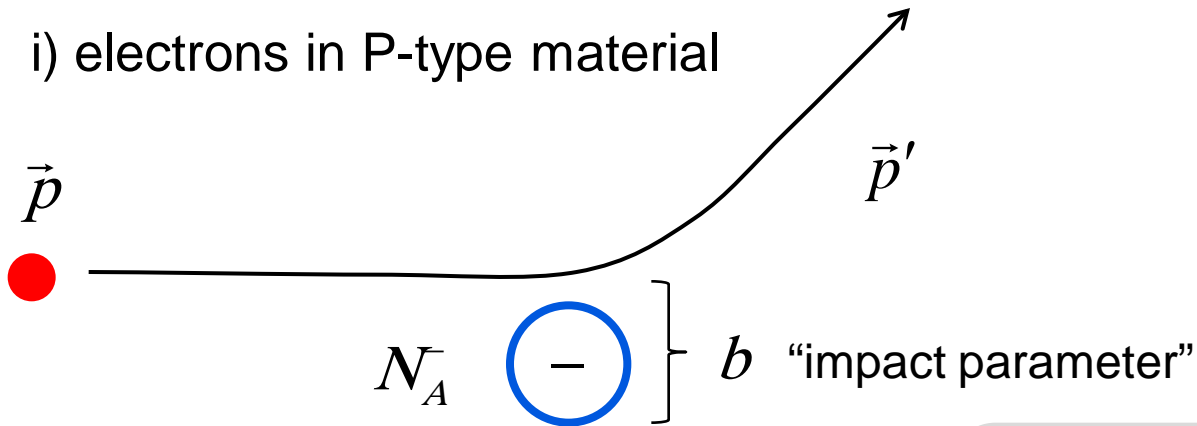
$$S(\vec{p}, \vec{p}') = \frac{2\pi}{\hbar} |H_{p'p}|^2 \delta(E' - E)$$

$$H_{\vec{p}', \vec{p}} = \int_{-\infty}^{+\infty} \psi_f^* U_s(\vec{r}) \psi_i d\vec{r}$$

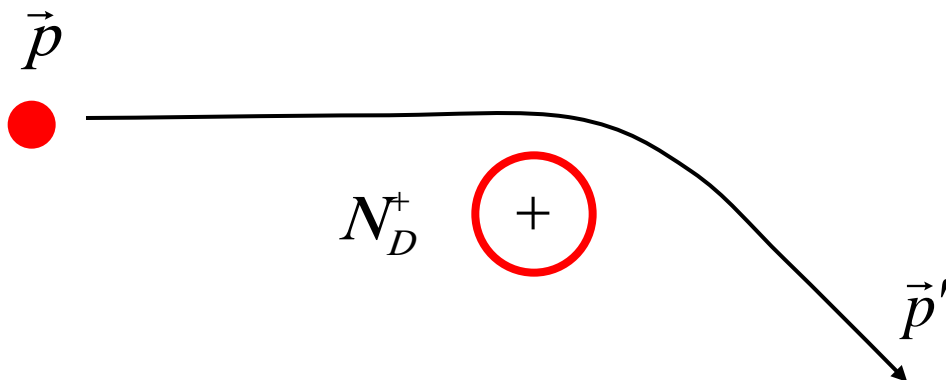
- 1) Identify the scattering potential
- 2) Compute the matrix element
- 3) Compute characteristic times

# scattering potential

i) electrons in P-type material



ii) electrons in N-type material



$$U_S(\vec{r}) = \pm \frac{q^2}{4\pi\kappa_S\epsilon_0 r}$$

According to FGR, the transition rate is independent of the sign of the scattering potential.

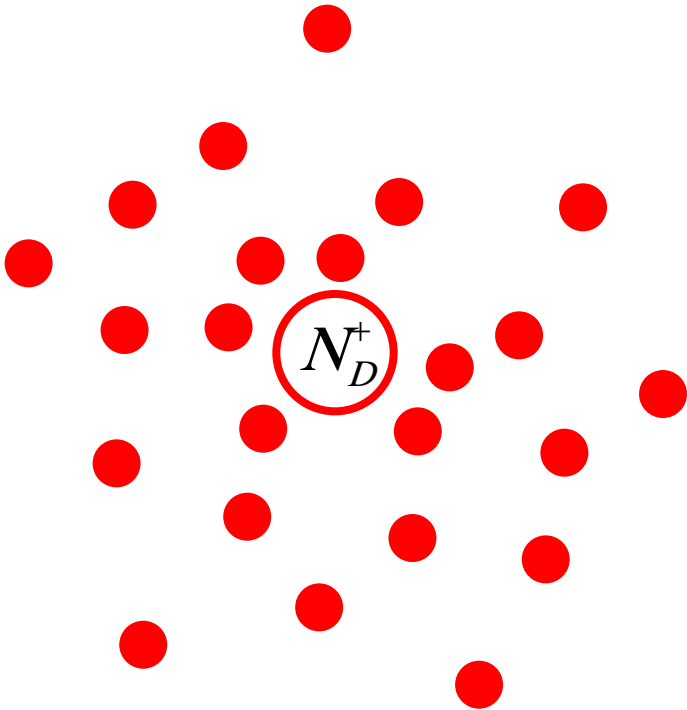
# outline

---

- 1) Review
- 2) Screening**
- 3) Brooks-Herring approach
- 4) Conwell-Weisskopf approach
- 5) Discussion
- 6) Summary / Questions

# screening

---



Bare Coulomb potential.

$$U_S(\vec{r}) = \frac{q^2}{4\pi\kappa_S\epsilon_0 r}$$

Screened Coulomb potential: ??

Mobile charges attracted to fixed charges “screen” out the fixed charge.

# screening in 3D

$$\nabla^2 V(\vec{r}) = -\frac{\rho}{\kappa_S \epsilon_0} = -\frac{q [N_D^+ - n(\vec{r})]}{\kappa_S \epsilon_0}$$

$$\frac{1}{L_D^2} \equiv \frac{q}{\kappa_S \epsilon_0} \frac{\partial n(\vec{r})}{\partial V}$$

$$n(\vec{r}) \approx N_D^+ = n_0$$

$$n(\vec{r}) = \frac{1}{\Omega} \sum_{\vec{k}} f_0(k)$$

$$V(\vec{r}) = V_0$$

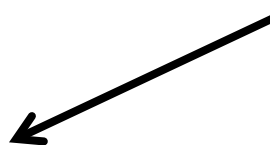
$$f_0(k) = \frac{1}{1 + e^{(E_C(\vec{r}) + E(\vec{k}) - E_F)/k_B T}}$$

$$\delta n(\vec{r}) \approx n(\vec{r}) - n_0$$

$$\frac{\partial n(\vec{r})}{\partial V} = q \frac{\partial n(\vec{r})}{\partial E_F}$$

$$\delta V(\vec{r}) \approx V(\vec{r}) - V_0$$

$$\frac{1}{L_D^2} \equiv \frac{q^2}{\kappa_S \epsilon_0} \frac{\partial n(\vec{r})}{\partial E_F}$$

$$\nabla^2 \delta V(\vec{r}) = -\frac{q}{\kappa_S \epsilon_0} \frac{\partial n(\vec{r})}{\partial V} \delta V(\vec{r})$$




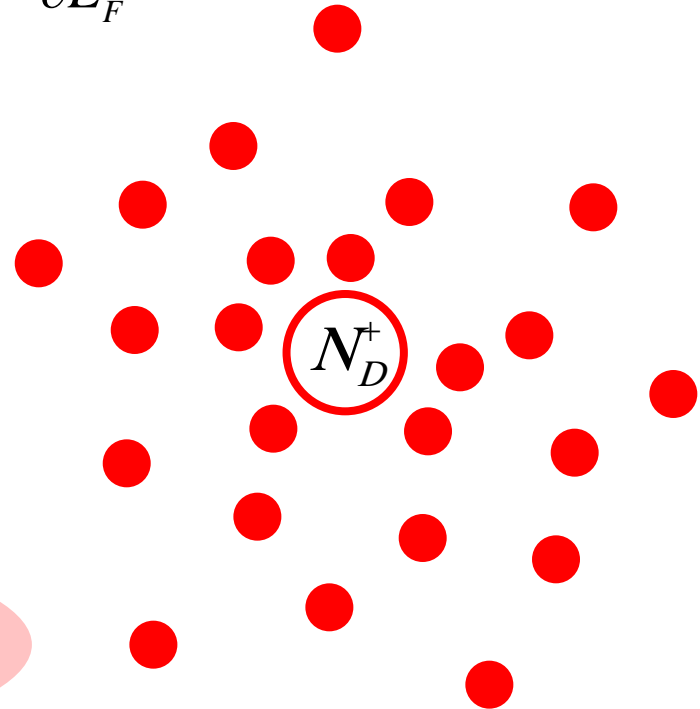
# screening in 3D

$$\nabla^2 \delta V(\vec{r}) = \frac{1}{L_D^2} \delta V(\vec{r}) \quad \frac{1}{L_D^2} \equiv \frac{q^2}{\kappa_S \epsilon_0} \frac{\partial n(\vec{r})}{\partial E_F}$$

$$\frac{1}{r^2} \frac{d}{dr} \left( r^2 \frac{dV}{dr} \right) = \frac{1}{L_D^2} \delta V(r)$$

$$\delta V(r) = C \frac{e^{-r/L_D}}{r}$$

$$U_S(r) = q\delta V(r) = \frac{q^2}{4\pi\kappa_S\epsilon_0 r} e^{-r/L_D}$$



# Debye length in 3D

$$U_S(r) = \frac{q^2}{4\pi\kappa_S\epsilon_0 r} e^{-r/L_D}$$

$$\frac{1}{L_D^2} \equiv \frac{q^2}{\kappa_S\epsilon_0} \frac{\partial n(\vec{r})}{\partial E_F} = \frac{q^2}{\kappa_S\epsilon_0 k_B T} \frac{\partial n(\vec{r})}{\partial \eta_F}$$

$$n_{3D} = N_{3D} \mathcal{F}_{1/2}(\eta_F)$$

$$\frac{\partial n_{3D}}{\partial \eta_F} = N_{3D} \mathcal{F}_{-1/2}(\eta_F) = n_{3D} \frac{\mathcal{F}_{-1/2}(\eta_F)}{\mathcal{F}_{1/2}(\eta_F)} = n_{3D} \quad (\text{non-degenerate})$$

$$L_D = \sqrt{\frac{\kappa_S \epsilon_0 k_B T}{q^2 n_0}}$$

Debye length  
(non-degenerate)

# comments on screening

---

- 1) Our semi-classical approach assumes that the potential is slowly varying on the scale of the electron's wavelength. For rapidly varying potentials, a more sophisticated approach is needed. (See Ashcroft and Mermin, pp. 340-343 for a discussion of the Lindhard theory.)
- 2) Our semi-classical approach also assumes that the potential is slowly in time. (See Ashcroft and Mermin, p. 344 for a brief discussion.)
- 3) For potentials that vary rapidly in space and time, a “dynamic screening” treatment is needed. (See chapter 9 in Ridley, *Quantum Processes in Semiconductors*, 4<sup>th</sup> Ed. and Chapter 10 in Ridley, *Electrons and Phonons in Semiconductor Multilayers*.)
- 4) Screening is generally less effective in 2D and in 1D. (See J.H. Davies, *The Physics of Low-Dimensional Structures*, pp. 350-356)

# outline

---

- 1) Review
- 2) Screening
- 3) Brooks-Herring approach**
- 4) Conwell-Weisskopf approach
- 5) Discussion
- 6) Summary / Questions

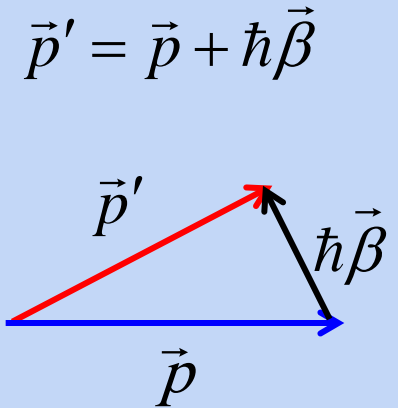
# transition rate and scattering potential

$$S(\vec{p}, \vec{p}') = \frac{2\pi}{\hbar} |H_{p',p}|^2 \delta(E' - E)$$

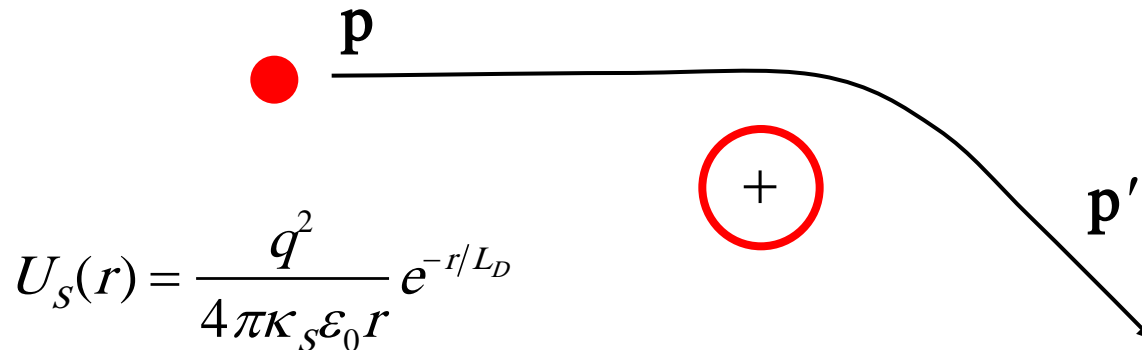
$$H_{p',p} = \frac{1}{\Omega} \int_{-\infty}^{+\infty} e^{-i\vec{p}'\cdot\vec{r}/\hbar} U_S(r) e^{i\vec{p}\cdot\vec{r}/\hbar} d\vec{r} = \frac{1}{\Omega} \int_{-\infty}^{+\infty} U_S(r) e^{-i(\vec{p}'-\vec{p})\cdot\vec{r}/\hbar} d\vec{r}$$

$$= \frac{1}{\Omega} \int_{-\infty}^{+\infty} U_S(r) e^{-i\vec{\beta}\cdot\vec{r}} d\vec{r} \equiv \frac{1}{\Omega} \tilde{U}_S(\vec{\beta})$$

$$S(\vec{p}, \vec{p}') = \frac{2\pi}{\hbar} \frac{1}{\Omega} |\tilde{U}_S(\vec{\beta})|^2 \delta(E' - E)$$

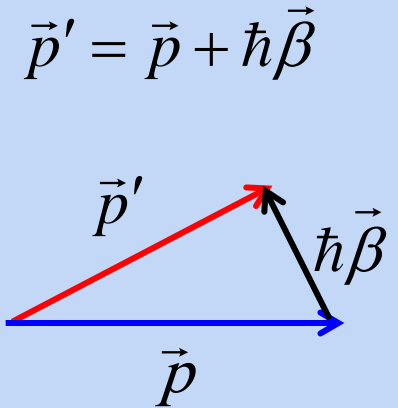


# II scattering (Brooks-Herring)



$$L_D = \sqrt{\frac{\kappa_S\epsilon_0 k_B T}{q^2 n_0}} \quad \text{Debye length}$$

$$\tilde{U}_S(\beta) = \int_{-\infty}^{+\infty} U_S(r) e^{-i\vec{\beta}\cdot\vec{r}} d\vec{r}$$



# Fourier transform of the screened Coulomb potential

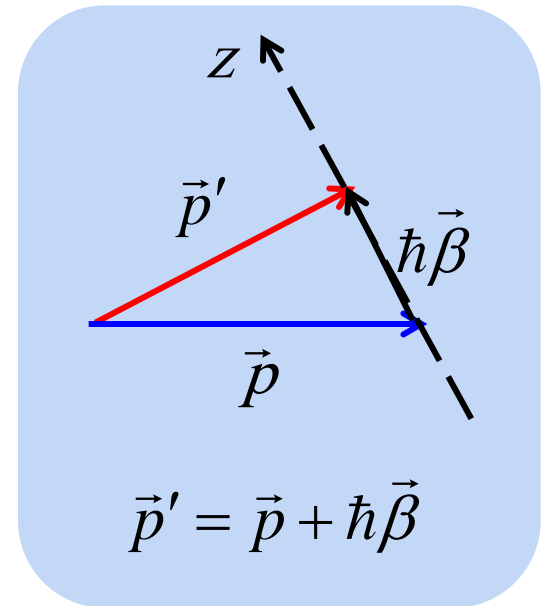
$$\tilde{U}_s(\beta) = \int_{-\infty}^{+\infty} \frac{q^2}{4\pi\kappa_s\epsilon_0 r} e^{-r/L_D} e^{-i\vec{\beta}\cdot\vec{r}} d\vec{r}$$

$$\tilde{U}_s(\beta) = \frac{q^2}{4\pi\kappa_s\epsilon_0} \int_0^{2\pi} d\phi \int_0^\pi \int_0^\infty e^{-r/L_D} e^{-i\vec{\beta}\cdot\vec{r}} r \sin\theta d\theta dr$$

$$\begin{aligned} \vec{\beta}\cdot\vec{r} &= \beta r \cos\theta \\ \sin\theta d\theta &= -d(\cos\theta) \end{aligned}$$

choose z-axis along  $\beta$ :

$$\tilde{U}_s(\beta) = \frac{q^2}{2\kappa_s\epsilon_0} \int_0^\infty e^{-r/L_D} r dr \underbrace{\int_{-1}^{+1} e^{-i\beta r \cos\theta} d(\cos\theta)}_{\frac{2 \sin(\beta r)}{\beta r}}$$



# Fourier transform (ii)

$$\tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0} \int_0^\infty \frac{e^{-r/L_D} \sin(\beta r)}{\beta} dr$$

$$\tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0 \Omega} \left( \frac{1}{\beta^2 + 1/L_D^2} \right)$$

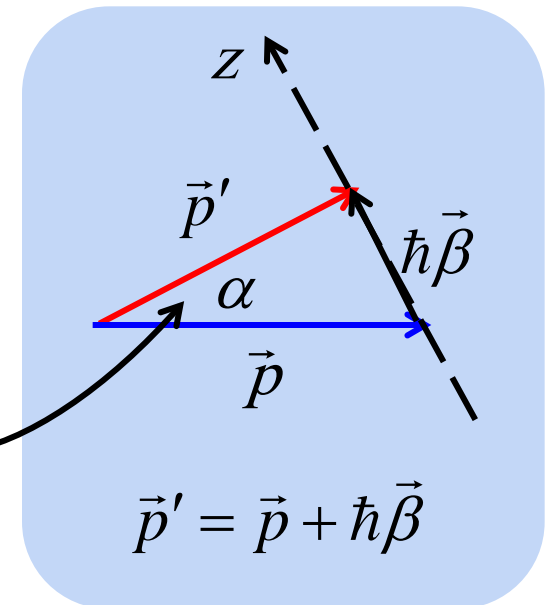
$$\tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0} \left( \frac{1}{4(p/h)^2 \sin^2(\alpha/2) + 1/L_D^2} \right)$$

$$\hbar\beta = 2p \sin(\alpha/2)$$

**small angle scattering preferred!!**

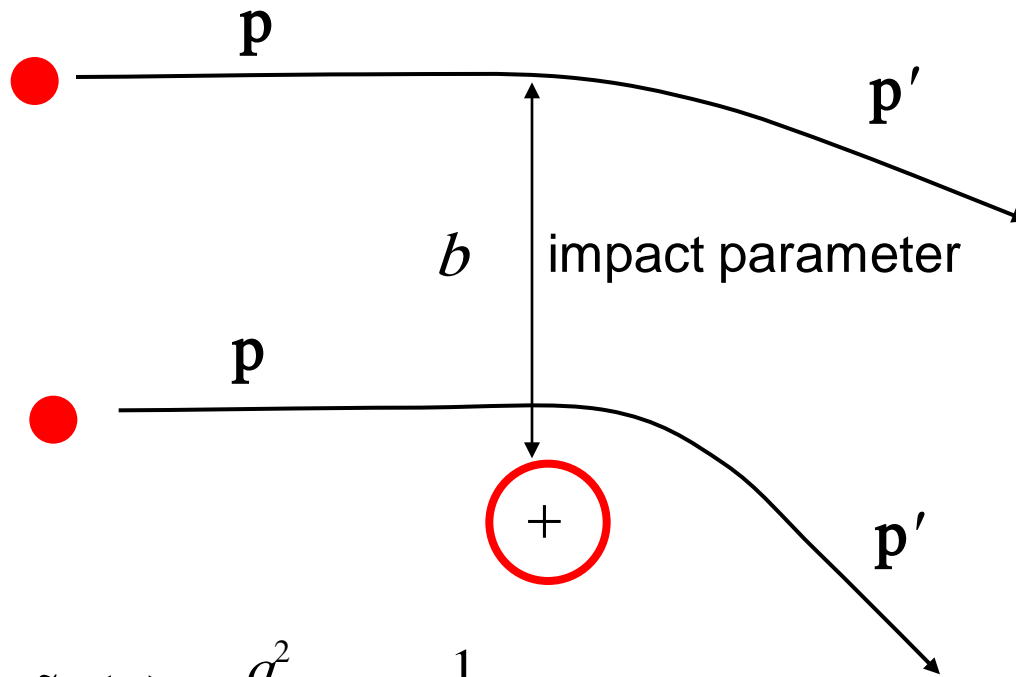
$$\vec{\beta} \cdot \vec{r} = \beta r \cos \theta$$

$$\sin \theta d\theta = -d(\cos \theta)$$





# small angle scattering



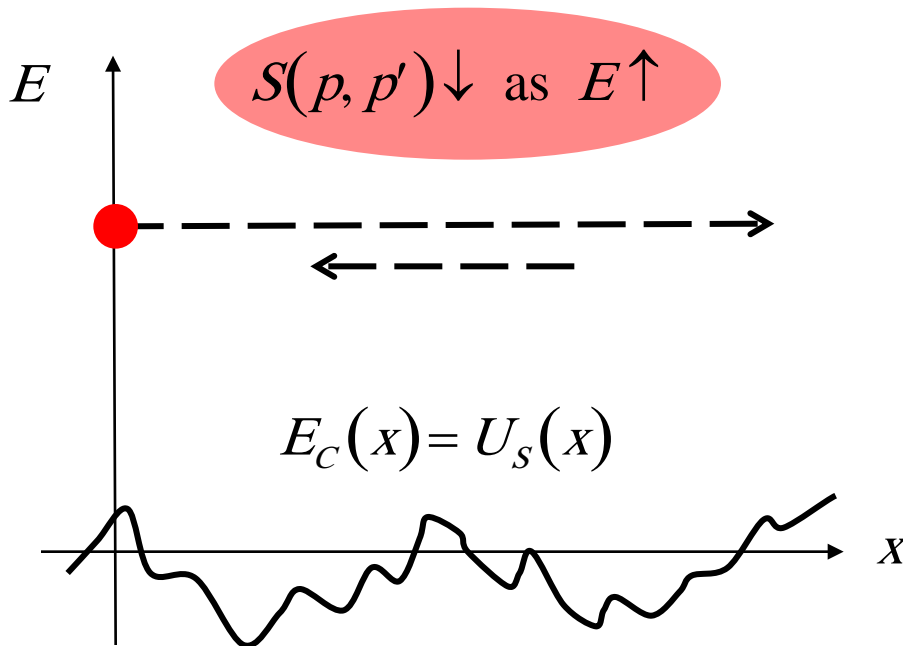
$$\tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0} \frac{1}{(\beta^2 + 1/L_D^2)}$$

$$U_s(r) = \frac{q^2}{4\pi\kappa_s\epsilon_0 r} e^{-r/L_D}$$

# II scattering of high energy carriers

$$\tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0} \left( \frac{1}{4(p/h)^2 \sin^2(\alpha/2) + 1/L_D^2} \right)$$

For a given deflection angle, higher energies scatter less.



Random charges introduce random fluctuations in  $E_C$ , which act as scattering centers.

High energy electrons don't "see" these fluctuations and are not scattered as strongly.

## II scattering: recap

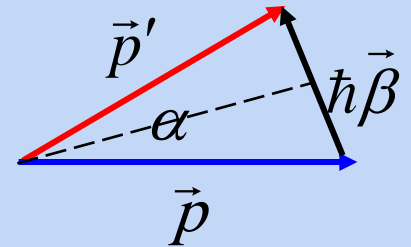
$$S(\vec{p}, \vec{p}') = \frac{2\pi}{\hbar} |H_{p',p}|^2 \delta(E' - E) \quad H_{p,p'} = \frac{1}{\Omega} \tilde{U}_s(\beta) \quad \tilde{U}_s(\beta) = \frac{q^2}{\kappa_s \epsilon_0} \frac{1}{(\beta^2 + 1/L_D^2)}$$

Need to multiple by the total number of ionized impurities in the volume,  $\Omega$ .

$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_s^2 \epsilon_0^2 \Omega} \frac{\delta(E' - E)}{(\beta^2 + 1/L_D^2)^2}$$

$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_s^2 \epsilon_s^2 \Omega} \frac{\delta(E' - E)}{\left( \frac{4p^2}{\hbar^2} \sin^2 \alpha/2 + 1/L_D^2 \right)^2}$$

$$\vec{p}' = \vec{p} + \hbar \vec{\beta}$$



$$\frac{\hbar \beta}{2} = p \sin \alpha/2$$

# examine result

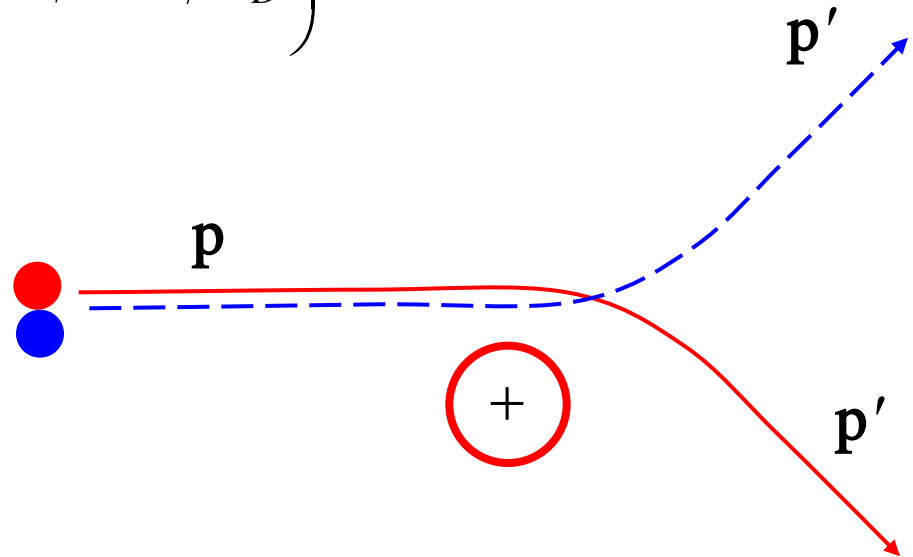
$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_s^2 \epsilon_0^2 \Omega} \frac{\delta(E' - E)}{\left( \frac{4p^2}{\hbar^2} \sin^2 \alpha/2 + 1/L_D^2 \right)^2}$$

1)  $S(\vec{p}, \vec{p}') \sim N_I$

2)  $S(\vec{p}, \vec{p}') \sim q^4$

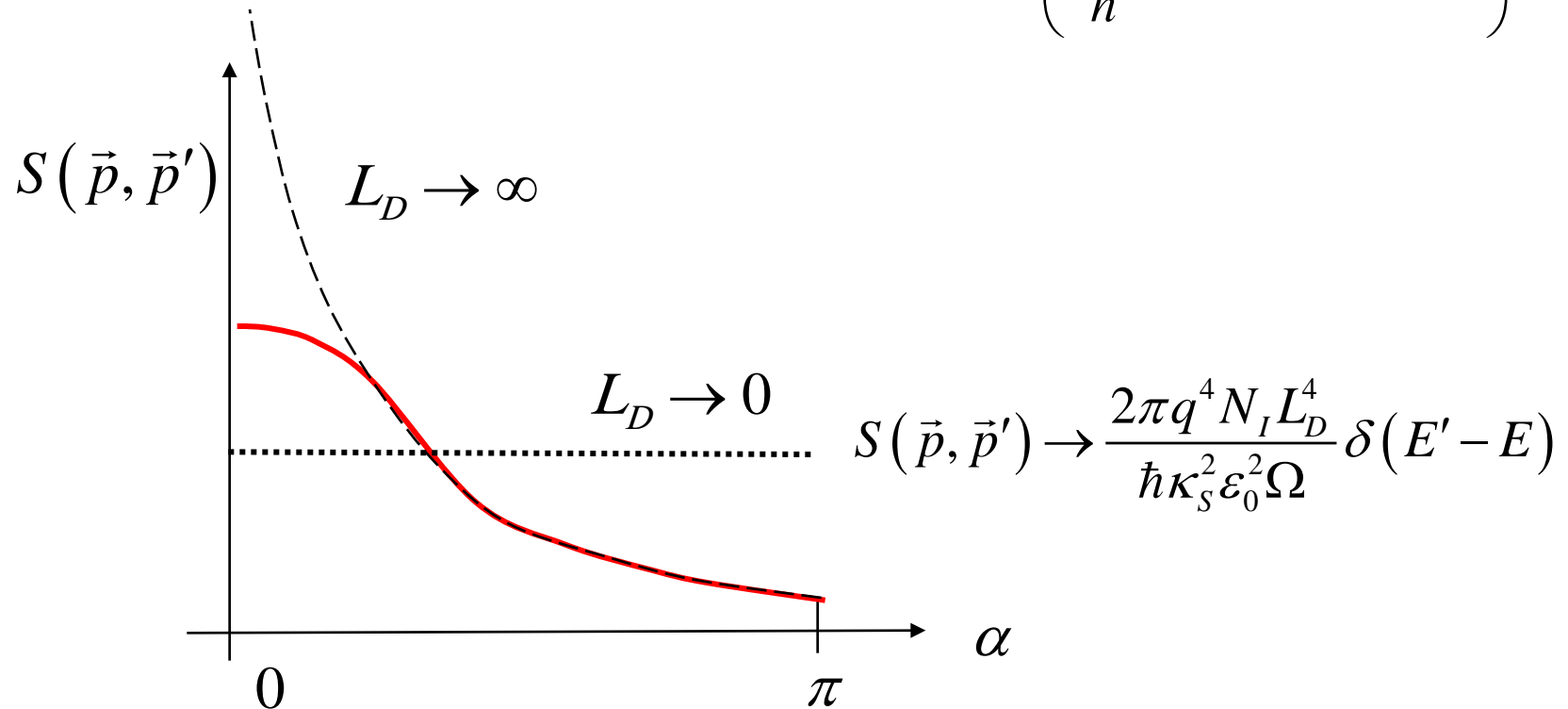
3)  $S(\vec{p}, \vec{p}') \sim 1/E^2$

4) favors small angle scattering



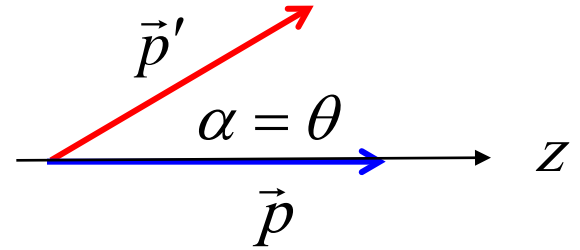
# examine result

4) angular dependence 
$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_S^2 \epsilon_0^2 \Omega} \frac{\delta(E' - E)}{\left( \frac{4p^2}{\hbar^2} \sin^2 \alpha/2 + 1/L_D^2 \right)^2}$$



# momentum relaxation time

$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') \left( 1 - \frac{p'}{p} \cos \alpha \right)$$



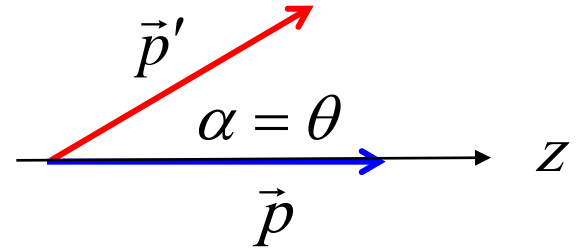
$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') (1 - \cos \alpha)$$

$S(\vec{p}, \vec{p}')$  favors small angles

expect:  $1/\tau_m < 1/\tau$     $\tau_m > \tau$

# momentum relaxation time

$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') (1 - \cos \alpha)$$



$$\tau_m(E) = \frac{16\sqrt{2m^*} \pi \kappa_s^2 \epsilon_0^2}{N_I q^4} \left[ \ln(1 + \gamma^2) - \frac{\gamma^2}{1 + \gamma^2} \right] E^{3/2}$$

$$\gamma^2 = 8m^* EL_D^2 / \hbar^2$$

See Lundstrom, pp. 69-70

$$\tau_m(E) \sim E^{3/2}$$

$$\tau_m(E) \approx \tau_0 \left( E / k_B T \right)^{3/2} \quad \tau_0 \sim T^{3/2} \quad s = 3/2$$

# outline

---

- 1) Review
- 2) Screening
- 3) Brooks-Herring approach
- 4) Conwell-Weisskopf approach**
- 5) Discussion
- 6) Summary / Questions



# BH vs.CW

---

Brook-Herring means “screened Coulomb scattering.”

Conwell-Weisskopf means “unscreened Coulomb scattering.”

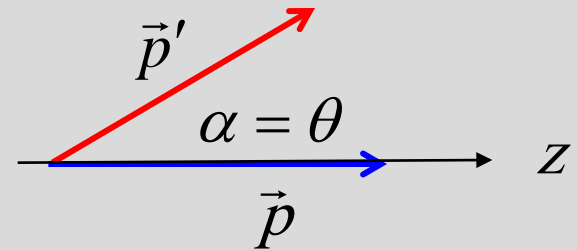
# Conwell-Weiskopf approach

$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_S^2 \epsilon_0^2 \Omega} \frac{\delta(E' - E)}{\left(\frac{4p^2}{\hbar^2} \sin^2 \alpha/2\right)^2}$$

unscreened Coulomb potential

$$S(\vec{p}, \vec{p}') \rightarrow \infty \quad \text{as} \quad \alpha \rightarrow 0$$

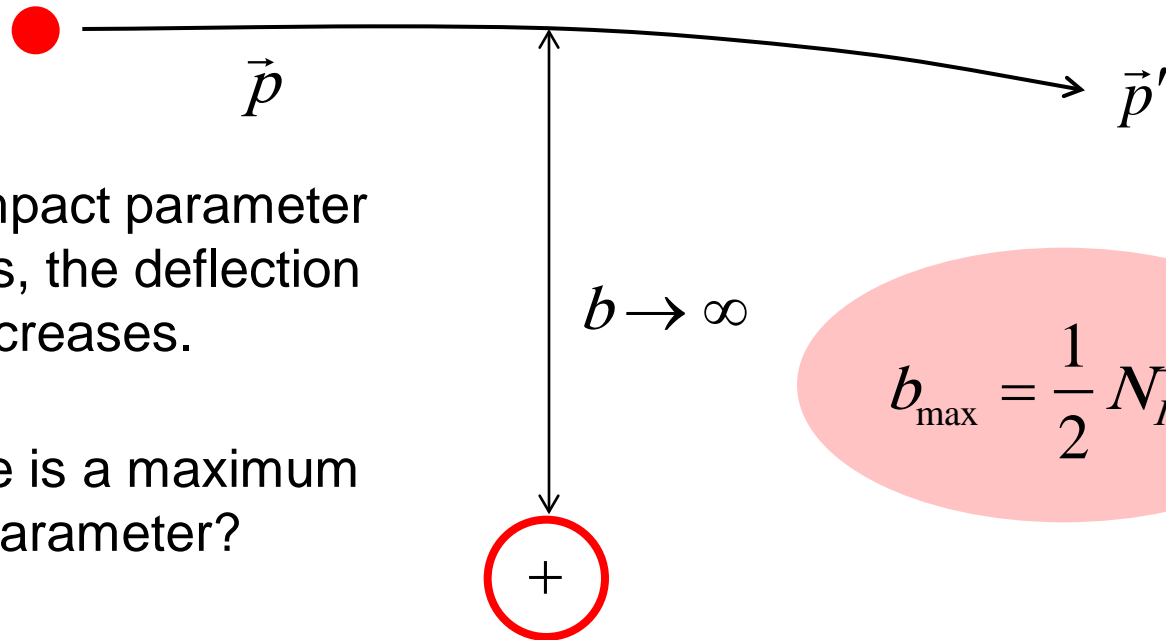
$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') (1 - \cos \alpha)$$



Can we specify a minimum angle, so that the integral does not blow up?

# Conwell-Weiskopf approach

$$S(\vec{p}, \vec{p}') = \frac{2\pi q^4 N_I}{\hbar \kappa_s^2 \epsilon_0^2 \Omega} \frac{\delta(E' - E)}{\left( \frac{4p^2}{\hbar^2} \sin^2 \alpha/2 \right)^2}$$



# Conwell-Weisskopf approach

---

$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') (1 - \cos \alpha)$$

$$\frac{1}{\tau_m} = \frac{\Omega}{(2\pi)^3} \int_0^{2\pi} d\phi \int_{\alpha_{\min}}^{\pi} S(\vec{p}, \vec{p}') (1 - \cos \alpha) \sin \alpha d\alpha p'^2 dp'$$

$$b_{\max} = \frac{q^2}{8\pi\kappa_s \epsilon_0 E(p)} \cot(\alpha_{\min}/2) \quad (\text{Rutherford})$$

# Conwell-Weisskopf approach

$$\frac{1}{\tau_m} = \sum_{\vec{p}'} S(\vec{p}, \vec{p}') (1 - \cos \alpha)$$

$$\tau_m(E) = \frac{16\pi\sqrt{2m^*}\kappa_s^2\epsilon_0^2}{N_I q^4} \left[ \frac{1}{\ln(1 + \gamma_{CW}^2)} \right] E^{3/2} \quad \gamma_{CW}^2 = b_{\max} / (q^2 / 8\pi\kappa_s\epsilon_0 E)$$

$$\tau_m(E) \sim E^{3/2}$$

$$\tau_m(E) \approx \tau_0 \left( E/k_B T \right)^{3/2} \quad \tau_0 \sim T^{3/2} \quad s = 3/2$$

Much like the Brooks-Herring result.

# CW vs. BH

---

Compare  $b_{MAX}$  to  $L_D$

Use BH if:

$$b_{\max} > L_D$$

$$b_{\max} = \frac{1}{2} N_I^{-1/3}$$

$$L_D = \sqrt{\frac{\kappa_S \epsilon_0 k_B T}{q^2 n_0}}$$

# outline

---

- 1) Review
- 2) Screening
- 3) Brooks-Herring approach
- 4) Conwell-Weisskopf approach
- 5) Discussion**
- 6) Summary / Questions

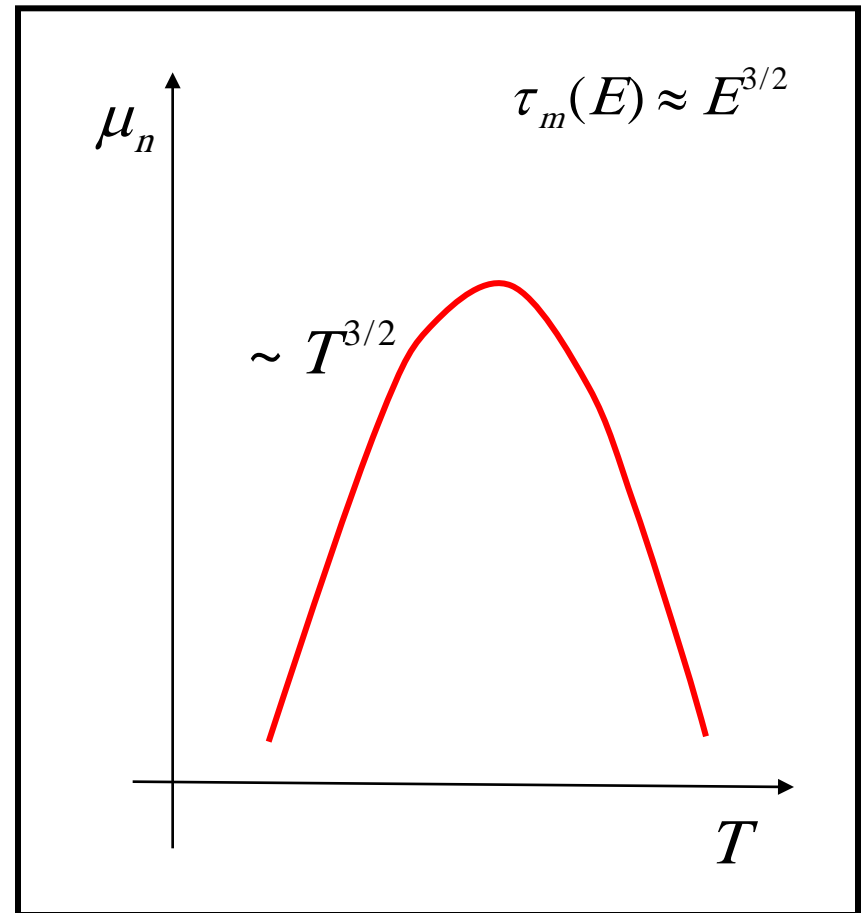
# mobility

$$\mu_n = \frac{q \langle \langle \tau_m \rangle \rangle}{m^*}$$

$$\langle \langle \tau_m \rangle \rangle = \tau_0 \frac{\Gamma(s + 5/2)}{\Gamma(5/2)} \quad s = 3/2$$

$$\mu_n = \frac{q\tau_0}{m^*} \frac{3\sqrt{\pi}}{4} \sim T^{3/2}$$

$T^{3/2}$  temperature dependence is the “signature” of charged impurity scattering.

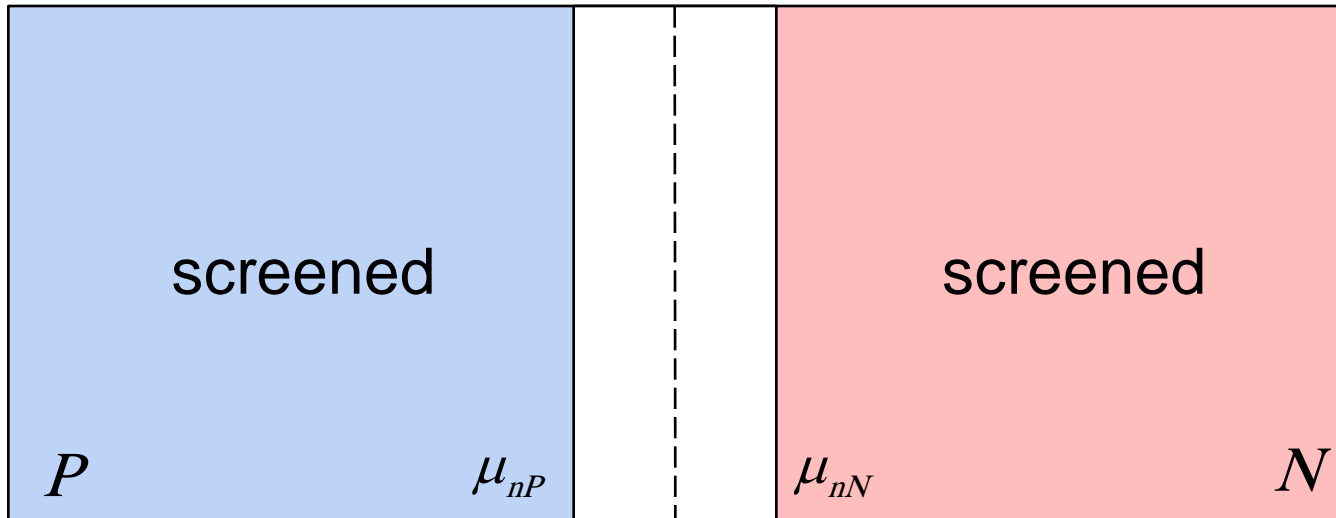




# PN junction

$$U_s(r) = + \frac{q^2}{4\pi\kappa_s\epsilon_0 r} e^{-r/L_D}$$

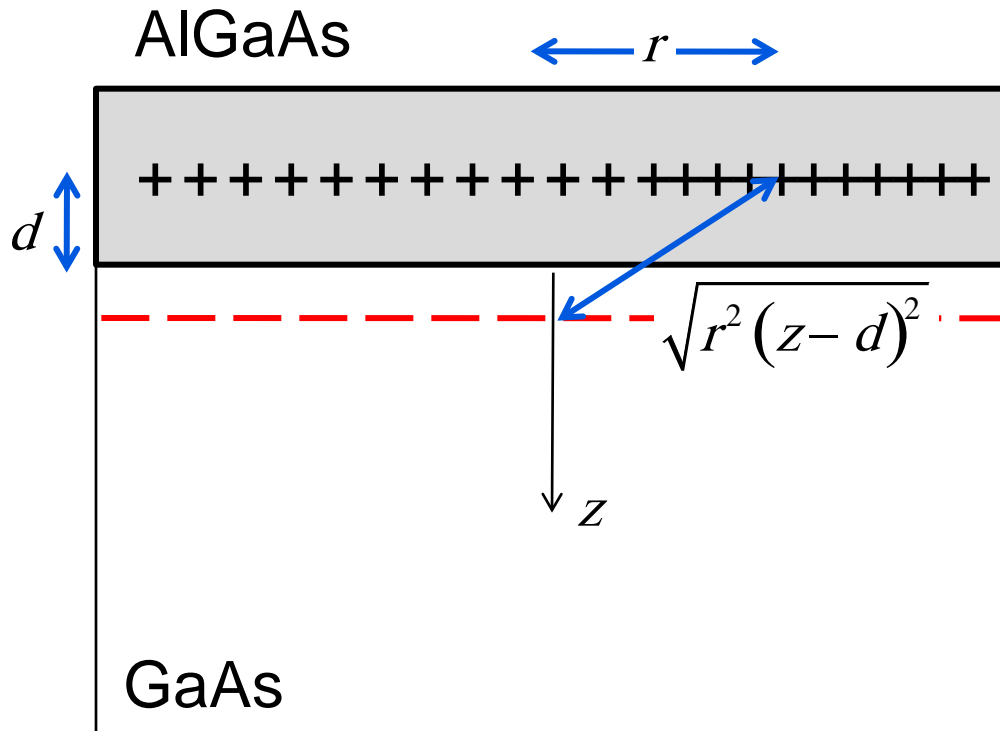
$$U_s(r) = - \frac{q^2}{4\pi\kappa_s\epsilon_0 r} e^{-r/L_D}$$



$$U_s(r) = + \frac{q^2}{4\pi\kappa_s\epsilon_0 r} \quad U_s(r) = - \frac{q^2}{4\pi\kappa_s\epsilon_0 r}$$

unscreened

# screening 2D modulation-doped layers



← delta doped layer

← centroid of electron wavefunction

The heterojunction interface can be atomically smooth and at low temperatures, phonon scattering is absent, so scattering by remove impurities dominates.

Extraordinarily high mobilities (e.g.  $> 10^6 \text{ cm}^2/\text{V-s}$ ) can be achieved at about  $T = 1\text{K}$ .

# modulation-doped structures

---

For a discussion of modulation doping, screening in 2D, and remote impurity scattering in 2D, see:

J.H. Davies, *The Physics of Low-Dimensional Semiconductors*, Chapter 8, Cambridge Univ. Press, 1998.

# questions

---

- 1) Review
- 2) Screening
- 3) Brooks-Herring approach
- 4) Conwell-Weisskopf approach
- 5) Discussion
- 6) Summary / Questions

